

# isc N-Channel Mosfet Transistor

2SK3878

### **FEATURES**

- Drain Current –I<sub>D</sub>= 9A@ T<sub>C</sub>=25°C
- · Drain Source Voltage-
  - : V<sub>DSS</sub>= 900V(Min)
- · Static Drain-Source On-Resistance
  - :  $R_{DS(on)} = 1.3 \Omega (Max)$
- · Avalanche Energy Specified
- · Fast Switching
- Simple Drive Requirements
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

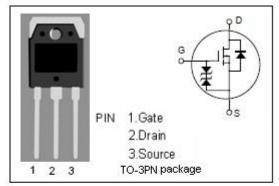
### **APPLICATIONS**

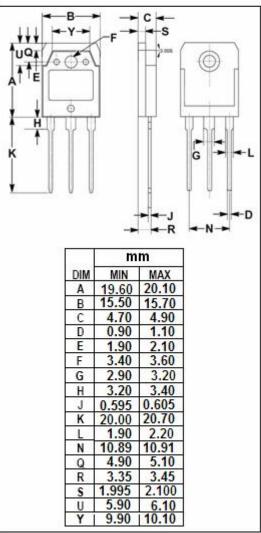
Designed for a load switch or in PWM applications

## • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT				
V <sub>DSS</sub>	Drain-Source Voltage	900	V				
$V_{GS}$	Gate-Source Voltage-Continuous	ge-Continuous ±30					
I <sub>D</sub>	Drain Current-Continuous 9		Α				
I <sub>DM</sub>	rain Current-Single Plused 27		Α				
P <sub>D</sub>	Total Dissipation @T <sub>C</sub> =25°C	150	W				
Tj	Max. Operating Junction Temperature	rating Junction Temperature 150					
T <sub>stg</sub>	Storage Temperature -55~150		$^{\circ}$				
• THERMAL CHARACTERISTICS							
SYMBOL	PARAMETER		UNIT				
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	0.833	°C/W				
R <sub>th j-a</sub>	Thermal Resistance, Junction to Ambient	50	°C/W				

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#### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> = 0.25mA	900		V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> ; I <sub>D</sub> = 1.0mA	3	5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> = 4.0A		1.3	Ω
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> = ±30V; V <sub>DS</sub> = 0		±100	nA
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 900V; V <sub>GS</sub> = 0		10	μА
V <sub>SD</sub>	Forward On-Voltage	I <sub>S</sub> = 9A; V <sub>GS</sub> = 0		1.4	V



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